

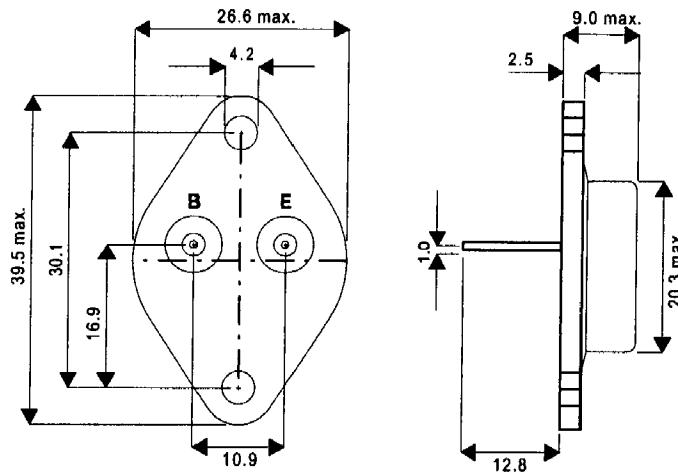
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MECHANICAL DATA

Dimensions in mm



TO3 Package.

Case is collector.

NPN DARLINGTON POWER TRANSISTOR **BDX69** **BDX69A** **BDX69B** **BDX69C**

NPN Darlington transistors for audio output stages and general amplifier and switching applications.

PNP complements are:
BDX68, **BDX68A**, **BDX68B**, **BDX68C**.

ABSOLUTE MAXIMUM RATINGS

($T_{case} = 25^\circ\text{C}$ unless otherwise stated)

		BDX 69	BDX 69A	BDX 69B	BDX 69C
V_{CBO}	Collector – Base Voltage (Open Emitter)	80V	100V	120V	140V
V_{CEO}	Collector – Emitter Voltage (Open Base)	60V	80V	100V	120V
V_{EBO}	Emitter – Base Voltage (Open Collector)	5V	5V	5V	5V
I_C	Collector Current			25A	
I_{CM}	Collector Current (Peak)			40A	
I_B	Base Current			500mA	
P_{tot}	Total Power Dissipation at $T_{MB} = 25^\circ\text{C}$			200W	
T_J	Maximum Junction Temperature			200°C	
T_{STG}	Storage Junction Temperature			–65 to 200°C	
$R_{\theta J-MB}$	Thermal Resistance, Junction to Mounting Base.			0.875°C / W	

**BDX69
BDX69A
BDX69B
BDX69C**

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Units
I_{CBO} Collector Cut-off Current	$I_E = 0$ $V_{CB} = V_{CBOmax}$			2	mA
	$I_E = 0$ $V_{CB} = \frac{1}{2}V_{CBOmax}$ $T_J = 200^\circ\text{C}$			10	
I_{CEO} Collector Cut-off Current	$I_B = 0$ $V_{CE} = \frac{1}{2}V_{CEOmax}$			6	mA
I_{EBO} Emitter Cut-off Current	$I_C = 0$ $V_{EB} = 5\text{V}$			10	mA
h_{FE}^* D.C. Current Gain	$I_C = 5\text{A}$ $V_{CE} = 3\text{V}$		3000		—
	$I_C = 20\text{A}$ $V_{CE} = 3\text{V}$		1000		
	$I_C = 30\text{A}$ $V_{CE} = 3\text{V}$		4000		
V_{BE}^* Base – Emitter Voltage	$I_C = 20\text{A}$ $V_{CE} = 3\text{V}$			2.5	V
V_{CEsat}^* Collector – Emitter Saturation Voltage	$I_C = 20\text{A}$ $I_B = 80\text{mA}$			2	V
C_c Collector Capacitance	$I_E = I_e = 0$ $V_{CB} = 10\text{V}$ $f = 1\text{MHz}$		600		pF
f_{hfe} Cut-off Frequency	$I_C = 10\text{A}$ $V_{CE} = 3\text{V}$		50		kHz
$ h_{fe} $ Small Signal Current Gain	$I_C = 10\text{A}$ $V_{CE} = 3\text{V}$ $f = 1\text{MHz}$		20		—
V_F Diode, Forward Voltage	$I_F = 20\text{A}$		2.5		V
t_{on} Turn-on Time	$I_{Con} = 20\text{A}$		1		μs
t_{off} Turn-off Time	$I_{Bon} = -I_{Boff} = 80\text{mA}$		3.5		

* Pulse Test: $t_p < 300\mu\text{s}$, $\delta < 2\%$